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### X-ray, Dielectric and High Pressure Studies on a Compound Exhibiting Ferro-, Ferri- and Antiferroelectric Smectic Phases

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# X-ray, Dielectric and High Pressure Studies on a Compound Exhibiting Ferro-, Ferri- and Antiferroelectric Smectic Phases

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We report X-ray layer spacing, dielectric constant and high pressure measurements on a compound that exhibits the following sequence of phase transitions: smectic A-ferroelectric smectic C\*-ferrielectric smectic C\*-antiferroelectric smectic C\*-hexatic antiferroelectric smectic I\*-crystal K. The pressure-temperature diagram shows two *three-phase* meeting points, which are topologically consistent with critical end points, and reentrant behavior of the C\* and C<sub>γ</sub> phases as the pressure is varied at *constant* temperature.

**Keywords:** Ferroelectric; ferrielectric; antiferroelectric; smectics; X-ray; dielectric constant; high pressure studies; pressure temperature phase diagram; critical end point

## INTRODUCTION

Studies on materials exhibiting the antiferroelectric and ferrielectric smectic phases have gained considerable importance in recent years [1]. In this paper we report X-ray, dielectric and high pressure studies on a new compound showing smectic A-ferroelectric smectic C\*-ferrielectric smectic C<sub>γ</sub>-antiferroelectric smectic C\*-hexatic antiferroelectric smectic I<sub>A</sub> phase

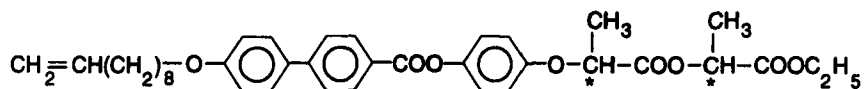
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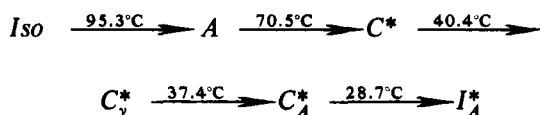
sequence. We also present new results on the effect of pressure on the  $C^* - C_\gamma^*$ ,  $C_\gamma^* - C_A^*$  and  $C_A^* - I_A^*$  phase boundaries.

## EXPERIMENTAL

Experiments have been conducted on 1-(R)-[1-(S)(ethyloxy carbonyl) ethoxy carbonyl] ethyloxycarbonyl 4'-(9-decenyloxy) biphenyl-4-carboxylate. The structural formula and the transition temperatures (as obtained by DSC) for this compound are given below, while the details regarding its synthesis will be reported elsewhere.



(R, S)



The optical textural changes across  $C^* - C_\gamma^*$  and  $C_\gamma^* - C_A^*$  transitions were closely similar to the ones described by Faye *et al.* [2]. The texture of the  $I_A^*$  phase was also seen to resemble the standard texture for smectic I described in the literature. With these observations, together with the X-ray and dielectric studies to be presented below, all the phases could be identified unambiguously.

For X-ray layer spacing measurements, a computer controlled diffractometer (Huber 644) was used [3]. The sample contained in a sealed Lindemann glass capillary of 0.5 mm diameter was aligned by cooling from the isotropic phase in the presence of a magnetic field. The layer spacing in the  $I_A^*$  phase could not be determined because the sample invariably crystallised just before  $C_A^* - I_A^*$  transition.

Dielectric measurements were made on 50  $\mu\text{m}$  thick samples contained in ITO coated glass cells treated with polyimide solution and rubbed. However, with 50  $\mu\text{m}$  thick samples, measurements were not possible in the  $I_A^*$  phase because the material crystallised in the  $C_A^*$  phase just before the  $C_A^* - I_A^*$  transition. With 9  $\mu\text{m}$  samples, on the other hand, crystallisation did not take place and measurements on the  $I_A^*$  phase were possible. The temperature was controlled by a hot stage-processor combination (Mettler

FP82-FP90). To improve the precision in measuring the sample temperature, a calibrated bead thermistor (YSI 44011) was located very close to the sample. The thermistor output was read on a digital multimeter (HP 34401A). The frequency, temperature and bias field dependence of the dielectric constant was measured using an impedance analyser (HP 4194A). The multimeter, the impedance analyser and the Mettler processor were interfaced to a PC for data acquisition and control.

High pressure studies were carried out using an optical cell with the sample sandwiched between sapphire windows and isolated from the pressure transmitting fluid by an elastomer tube. The transition temperatures were determined by the optical transmission technique (For details of this set-up see Ref. 4). In contrast to what happens at atmospheric pressure, the  $I_A^*$  phase supercooled appreciably at elevated pressures.

## RESULTS AND DISCUSSION

Figure 1 shows the layer spacing  $d$  as a function of temperature in the  $A$ ,  $C^*$ ,  $C_\gamma^*$  and  $C_A^*$  phases. At the  $A - C^*$  transition, there is an abrupt change in the slope of  $d$  vs. temperature but as there is no discontinuity in the value of  $d$ , nor a two-phase coexistence region, the transition may be taken to be of second order. At the  $C^* - C_\gamma^*$  and  $C_\gamma^* - C_A^*$  transitions neither the

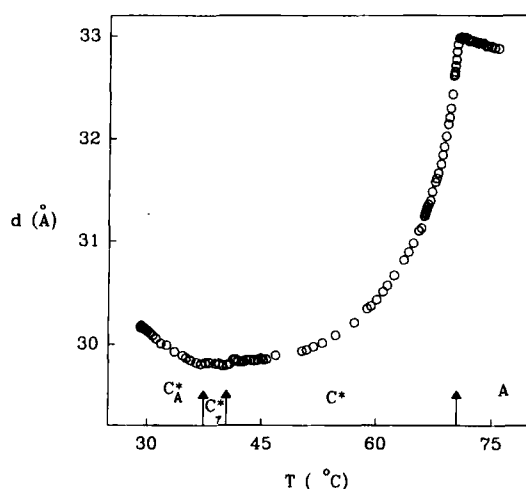


FIGURE 1 Temperature dependence of the layer spacing. The arrows indicate the transition temperatures determined by DSC. Owing to the crystallisation of the sample, no data could be obtained in the  $I_A^*$  phase.

magnitude of  $d$  nor its slope hardly change. These features are in agreement with earlier observations [5]. In the  $C_A^*$  phase, just below the  $C_\gamma^* - C_A^*$  transition,  $d$  reverses its trend and starts increasing with decreasing temperature. This increase can be interpreted as due to the occurrence of the hexatic  $I_A^*$  phase below  $C_A^*$ . However, as mentioned earlier, X-ray measurements in  $I_A^*$  phase could not be carried out because of the crystallisation of the sample. The variation of  $d$  in the  $C_A^*$  phase is very similar to that reported recently by Neundorff *et al.* [6] in a mixture of MHPOBC/MHO BMB, which also shows  $C_A^* - I_A^*$  transition.

The thermal variation of the dielectric constant  $\epsilon'$  at different frequencies is plotted in Figure 2a. Near the  $A - C^*$  transition, there is a rapid increase in the value of  $\epsilon'$ , the magnitude of which decreases as the frequency is increased. The features are explainable in terms of the contribution due to the two relaxation modes, viz., the Goldstone mode and the soft mode. As the temperature is lowered, around  $40^\circ\text{C}$  there is a large drop in  $\epsilon'$  values at low frequencies and a small increase in the value for the high frequency

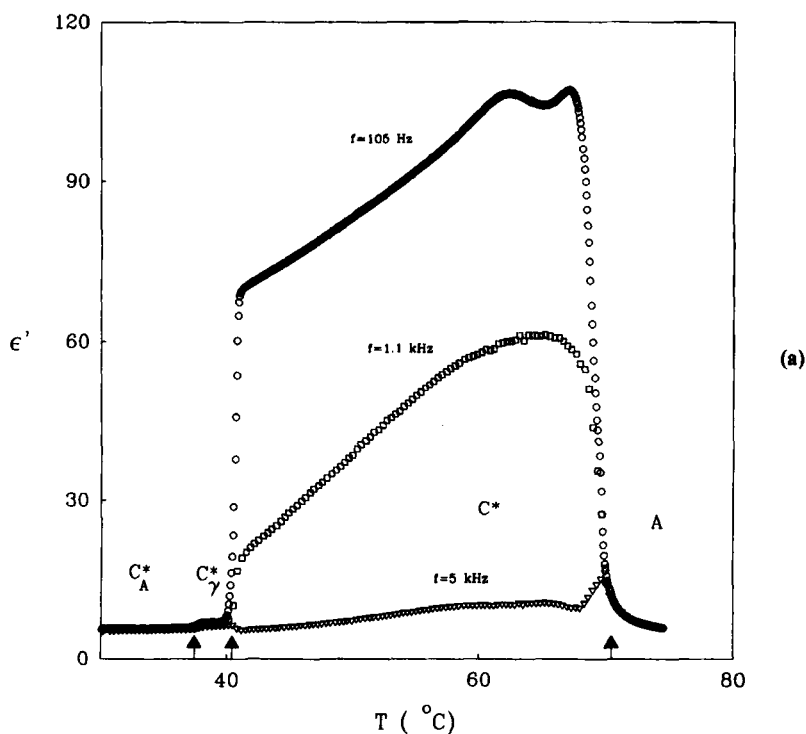


FIGURE 2

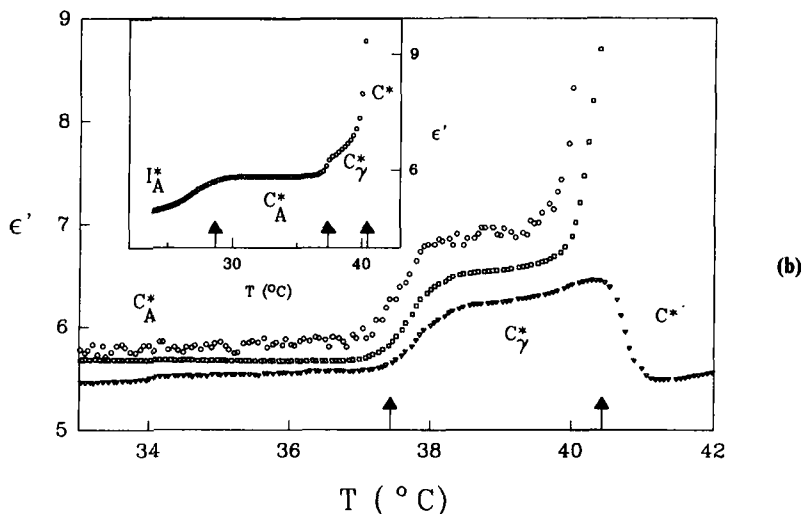


FIGURE 2 (a) Thermal variation of the real part of the transverse dielectric constant  $\epsilon'$  at three different frequencies obtained using  $50\mu\text{m}$  samples. For the sake of clarity, only every fifth point has been plotted for the 1.1 kHz and 5 kHz data sets. (b) data near the  $C^* - C_\gamma^*$  and  $C_\gamma^* - C_A^*$  transitions on an enlarged scale. The inset in (b) shows measurements near the  $C_A^* - I_A^*$  transition, obtained with  $9\mu\text{m}$  samples. The arrows indicate transition temperatures determined by DSC.

measurements. This temperature corresponds to the  $C^* - C_\gamma^*$  transition. In fact, the change is much sharper in the high frequency data (see Fig. 2b) and is therefore useful in locating the  $C^* - C_\gamma^*$  transition point. Finally, the  $C_\gamma^* - C_A^*$  transition is accompanied by a small but noticeable reduction in the  $\epsilon'$  values. These results can be seen as due to the influence of the Goldstone mode (recalling that the sample is quite thick). The contribution of this mode is large in the  $C^*$  phase, decreases in the  $C_\gamma^*$  phase and vanishes in the  $C_A^*$  phase.

We have already noted that with  $50\mu\text{m}$  samples, measurements were not possible in the  $I_A^*$  phase due to the crystallisation of the material. This was overcome by using a thinner sample ( $9\mu\text{m}$ ). The dielectric data in the  $I_A^*$  phase so obtained are shown in the inset of Figure 2b. The smooth variation across the  $C_A^* - I_A^*$  transition is perhaps indicative of a continuous evolution from one phase to another and confirms that  $I_A^*$  is antiferroelectric.

The temperature dependence of the relaxation frequency  $f_R$  and dielectric strength  $\Delta\epsilon$  obtained from dispersion measurements are shown in Figures 3 and 4. In the  $A$  phase, the relaxation is due to the soft mode. It is known that in the  $A$  phase, on approaching the  $A - C^*$  transition, the relaxation frequency of the soft mode decreases while its dielectric strength increases. In the  $C^*$  phase the dominant contribution is due to the Goldstone mode

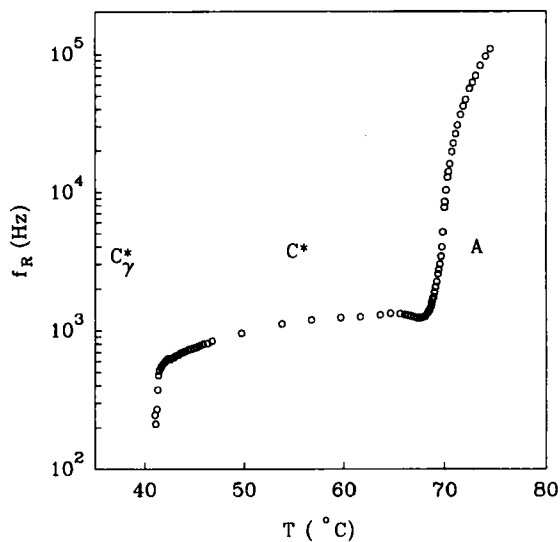


FIGURE 3 Plot of the dielectric relaxation frequency versus temperature.

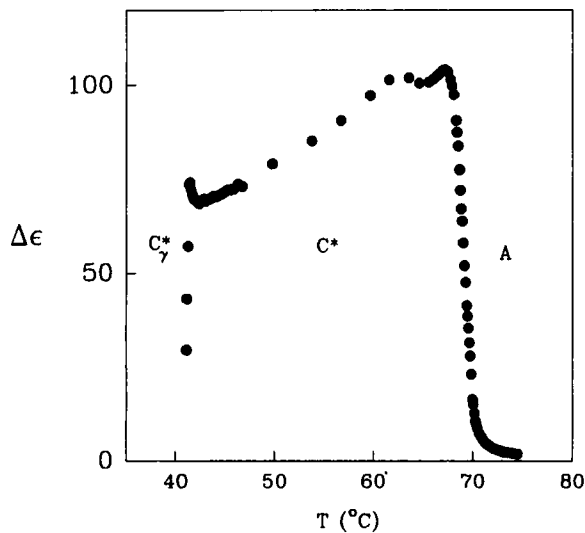


FIGURE 4 Dependence of the dielectric relaxation strength on temperature.

which masks the soft mode. The temperature dependence of the Goldstone mode relaxation frequency and the dielectric strength are primarily controlled by the thermal variation of the helical pitch. Experiments have shown that the value of the helical pitch is weakly dependent on temperature in the



$C^*$  phase away from the  $A - C^*$  transition, but drops abruptly close to it. Consequently the Goldstone parameters should show a strong temperature dependence in the vicinity of the  $A - C^*$  transition, a fact which is confirmed in the  $f_R$  and  $\Delta\epsilon$  data shown in Figures 3 and 4. Near the  $C^* - C_\gamma^*$  transition, there is a large decrease in  $f_R$  and a small increase in  $\Delta\epsilon$  followed by a sharp fall. A similar behaviour has been observed in earlier measurements [7]. In a recent paper, Hiller *et al.* [8] argue that the three-layer-block picture of  $C_\gamma^*$  phase could lead to a 3-fold increase in the helical pitch across the  $C^* - C_\gamma^*$  transition. In such a case, the relaxation frequency which is inversely proportional to square of the helical pitch should decrease by about an order of magnitude on going from the  $C^*$  to the  $C_\gamma^*$  phase, in broad agreement with our data.

It has been shown by Isozaki *et al.* [9] that in these systems the application of a DC field leads to a variety of temperature-electric field (T-E) phase diagrams. Their data were obtained through electro-optic tilt angle or conoscopic observations. As we could observe very clear signatures of different transitions in our dielectric measurements, we could readily map such phase diagrams accurately from the dielectric data. As mentioned earlier, the changes observed are much sharper when the probing frequency is high. Therefore we used the 5 kHz data to map the T-E phase diagram. The results are shown in Figure 5. Both the  $C^* - C_\gamma^*$  and  $C_\gamma^* - C_A^*$  boundaries

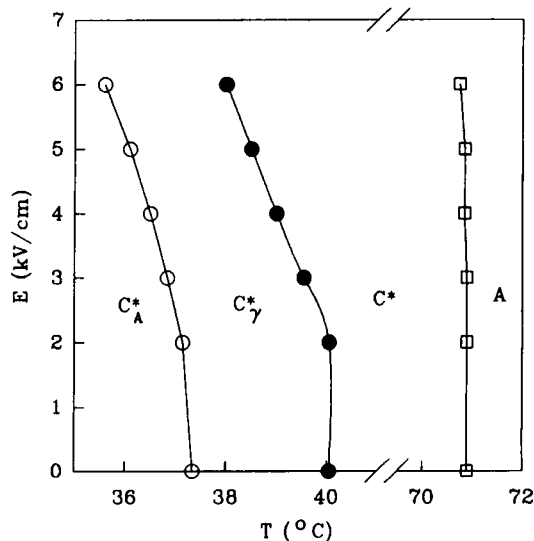


FIGURE 5 Temperature-electric field phase diagrams on the application of a DC bias field determined from dielectric measurements. The features bear good similarity to the ones obtained by the tilt angle/conoscopy method by Isozaki *et al.* [9].

have a negative slope while the  $A - C^*$  transition temperature is only very weakly dependent on the applied electric field. The present phase diagram is similar to the ones obtained on different materials using the tilt angle/cono-scopy method.

## PRESSURE STUDIES

Recently we have carried out a series of high pressure measurements aimed at mapping out the pressure-temperature (P-T) phase diagrams as also studying the effect of pressure on the electrical properties [10]. All these studies have been in the ferroelectric  $C^*$  phase and near the  $A - C^*$  transition. We have now investigated, to our knowledge the first time, the influence of pressure on the ferri- and antiferroelectric phases. The P-T diagram is shown in Figure 6a. As commonly observed, the transition temperatures of both the Isotropic-A and  $A - C^*$  boundaries increase with increasing pressure, the slopes being  $dT/dP = 31.3^\circ\text{C/kbar}$  and  $25^\circ\text{C/kbar}$  respectively. The  $C_A^* - I_A^*$  boundary also shows a positive slope with  $dT/dP = 16.3^\circ\text{C/kbar}$ . The  $C^* - C_\gamma^*$  and  $C_\gamma^* - C_A^*$  transition boundaries show more interesting results. At lower pressures their transition temperatures increase with increasing pressure, but around 2.5 kbar there is a reversal in the trend (see enlarged plot in Fig. 6b). The phase boundaries curl towards the  $C_\gamma^* - C_A^*$  line so that the  $C_\gamma^*$  and  $C_A^*$  phases get bounded resulting in two *three-phase* meeting points, namely,  $C_\gamma^* - C_A^* - I_A^*$  point at  $\sim 3.05$  kbar and  $C^* - C_\gamma^* - I_A^*$  point at  $\sim 3.2$  kbar. Notice that while the boundaries associated with the transition to the  $I_A^*$  phase go through the meeting points without any change in the slope, the  $C^* - C_\gamma^*$  and  $C_\gamma^* - C_A^*$  lines approach the respective meeting points at a finite angle. This feature, in fact, satisfies the topological requirement for a critical end point (CEP). The other "thermodynamic" condition to note is that at CEP the two boundaries which go through the meeting point without any slope change would be first-order in character while the other line must be second order. In the present case symmetry rules permit both the  $C^* - C_\gamma^*$  and  $C_\gamma^* - C_A^*$  transitions to be second order [11], but the  $C_A^* - I_A^*$  transition, like the  $C^* - I^*$  transition, can only be first order. These arguments suggest that the two meeting points may be critical end points. Detailed studies in the vicinity of the points should confirm this.

Another noteworthy feature observed in the phase diagram is the phenomenon of reentrance. In Figure 6b it is seen that at constant temperature, say  $\sim 80^\circ\text{C}$ , a sequence  $C_\gamma^* - C_A^* - C_\gamma^*$  is observed as the pressure is varied

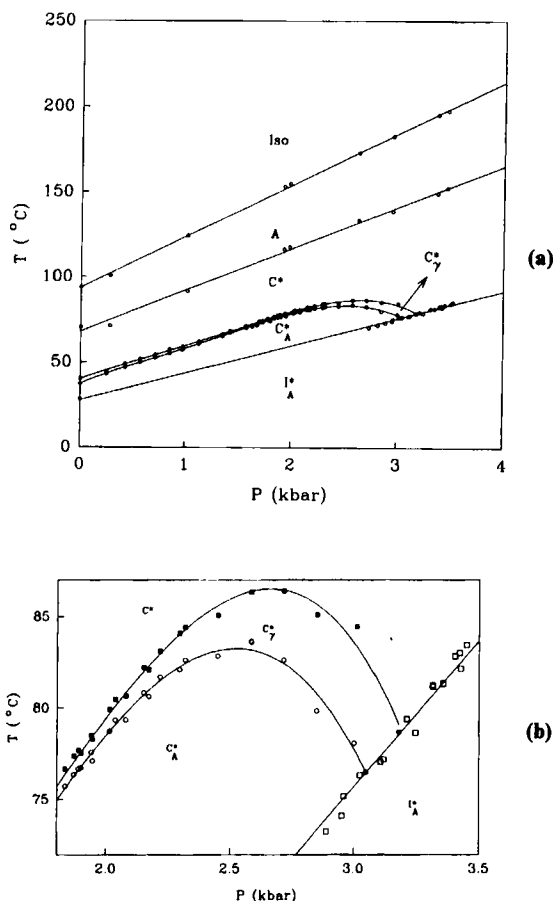


FIGURE 6 (a) Pressure-temperature phase diagram mapped using an optical transmission set up. While the  $Iso-A$ ,  $A - C^*$  and  $C_A^* - I_A^*$  boundaries have a positive slope throughout, the  $C^* - C_\gamma^*$  and  $C_\gamma^* - C_\gamma$  lines show a negative curvature at higher pressures. This results in the  $C^*$  and  $C_\gamma$  phases getting bound, leading to  $C^* - C_\gamma^* - I_A^*$  and  $C_\gamma^* - C_\gamma - I_A^*$  meeting points. The data near the two meeting points are shown on an enlarged scale in (b). The topologies near the meeting points are consistent with the critical end point topology. The phase diagram also brings out reentrant behavior of the  $C^*$  and  $C_\gamma^*$  phases as the pressure is varied at constant temperature.

i.e.,  $C_\gamma^*$  reenters. It may be mentioned that a reentrant  $C_\gamma^*$  phase has in fact been reported in the temperature-electric field phase diagram at room pressure for another compound [12]. Similarly it can be seen that the  $C^*$  phase reenters with varying pressure at constant temperature. We are planning to carry out pressure studies on a material having larger temperature range of the  $C_\gamma^*$  phase, which we believe may show a thermally-induced reentrant  $C_\gamma^*$  phase.

## References

- [1] See e.g., A. Fukuda, Y. Takanishi, T. Isozaki, K. Ishikawa and H. Takezoe, *J. Mater. Chem.*, **4**, 997 (1994).
- [2] V. Faye, J. C. Rouillon, C. Destrade and H. T. Nguyen, *Liquid Crystals*, **19**, 47 (1995).
- [3] S. Krishna Prasad, R. Shashidhar, B. R. Ratna, B. K. Sadashiva, G. Heppke and S. Pfeiffer, *Liq. Cryst.*, **2**, 111 (1987).
- [4] A. N. Kalkura, R. Shashidhar and N. Subramanya Raj Urs, *J. Physique*, **44**, 51 (1983).
- [5] A. Ikeda, Y. Takanishi, H. Takezoe, A. Fukuda, S. Inui, S. Kawano, M. Saito and H. Iwane, *Jpn. J. Appl. Phys.*, **30**, L1032 (1991).
- [6] M. Neundorff, Y. Takanishi, A. Fukuda, S. Saito, K. Murashiro, T. Inukai and D. Demus, *J. Mater. Chem.*, **5**, 2221 (1995).
- [7] M. Glogarova, H. Sverenyak, H. T. Nguyen and C. Destrade, *Ferroelectrics*, **147**, 43 (1993).
- [8] S. Hiller, S. A. Pikin, W. Haase, J. W. Goodby and I. Nishiyama, *Jpn. J. Appl. Phys.*, **33**, L1096 (1994).
- [9] T. Isozaki, T. Fujikawa, H. Takezoe, A. Fukuda, T. Hagiwara, Y. Suzuki and I. Kawanura, *Phys. Rev. B.*, **48**, 13439 (1993).
- [10] S. Krishna Prasad, S. M. Khened and S. Chandrasekhar, *Ferroelectrics*, **147**, 351 (1993).
- [11] V. L. Lorman, A. A. Bulbitch and P. Taledano, *Phys. Rev.*, **E49**, 1367 (1994).
- [12] H. Moritake, M. Ozaki, H. Taniguchi, K. Satoh and K. Yoshino, *Jpn. J. Appl. Phys.*, **33**, 5503 (1994).